arXiv:cond-mat/0301419v1 [cond-mat.supr-con] 22 Jan 2003

A density functional study of pressure induced superconductivity in P and its implication for spintronics.

S. Ostanin[1], V. Trubitsin[2], J.B. Staunton[1], S.Y. Savrasov[3]
[1]*Department of Physics, University of Warwick, Coventry CV4 7AL, United Kingdom*
[2]*Physico-Technical Institute, Ural Branch of RAS, 132 Kirov Str., 426001 Izhevsk, Russia and*
[3]*Department of Physics, New Jersey Institute of Technology, Newark, New Jersey 07102*
(Dated: February 2, 2008)

The stability of high-pressure phases of P has been studied using density functional theory and the local density approximation. Using a linear response technique, we have calculated the phonon spectrum and electron-phonon interaction for bcc P and predict it to be superconducting with T_c of 19 K. We propose that this phase might be realized in epitaxial thin films using templates such as V(100), Fe(100) or Cr(100) relevant to spintronics applications.

PACS numbers: 61.50.Ks, 74.25.Jb, 74.78.Fk, 85.75.-d

The study of properties of materials under pressure is a key experimental technique and recent discoveries of superconductivity in such simple metals as compressed Fe [1] and Li [2] are currently generating enormous interest [3, 4, 5]. Black insulating phosphorus, with an orthorhombic A17 structure, which is the most stable form at ambient conditions, exhibits a series of pressure induced phase transitions. [6, 7, 8, 9] The first is a transformation to a metallic phase with the simple cubic structure at 10 GPa. This phase is known to superconduct with T_c=10K [9]. An observation of a new simple bcc structure above 262 GPa has been made recently [7], which points out that similar or even stronger electron-phonon interaction and pressure induced superconductivity may be also realized in bcc P. Growth of P containing materials by thin film techniques has been developed very recently [10] to fabricate the class of wide gap phosphide ferromagnetic semiconductors which may provide an ideal opportunity to stabilize the bcc phase of P at ambient conditions using suitable templates such as the V(100), Fe(100) or Cr(100) substrates. This may lead to a significant breakthrough in technological spintronics applications in which combined spin and superconducting degrees of freedom will provide a new level of functionality for microelectronic devices.

In this work we address both the issue of the phase stability of P as well as the superconductivity of its highly pressurized bcc structure. We use density functional total energy [11] and linear response [12] techniques which have proven to provide a reliable description of various ground state properites for a large class of materials. We also study the electronic structure of the $Fe_5/P_n/Fe_4$ (n=3,5) superlattices, with the lattice constant of bulk Fe to investigate the problem of how to stabilize the bcc phase under ambient pressure conditions.

In the past, structural phase transformations in P have been the subject of many experimental [6, 7, 8, 9] and theoretical [13, 14, 15] density functional theory (DFT) based studies. Orthorhombic A17 structured P transforms to the rhombohedral A7 phase at 4.5 GPa.[6] The puckered P layers in the ambient-pressure A17 structure have strong covalent intralayer bonding and weak bonding between layers that result in an anisotropic compressibility. Under pressure, the distance between the interlayer P atoms in the A17 structure decreases faster than the intraplane distance forming the semimetallic A7 structure. This A7 phase, which is similar to the structure of such group-V elements as As, Sb, and Bi, undergoes a transition to the simple cubic (sc) metallic phase at 10 GPa.[6] In the group-V elements, this A7→sc transition is observed also in Sb at 7 GPa.

With increasing pressure, at 137 GPa, the sc structure transforms into a simple hexagonal (sh) one.[7] This sc→sh transition, which is accompanied by a large volume reduction of 7.6 %, is the first such observation reported for an elemental system. The sc-sh transformation probably occurs via an intermediate phase [7], and results in the change in the co-ordination number from 6 to 8. Since the sh structure has a low atomic packing fraction, namely 0.605, a phase with a higher packing fraction such as bcc, fcc or hcp should be expected at higher pressures. Indeed, with increasing pressure, the c/a ratio of the sh phase increases from 0.948 to 0.956, and, finally, above 262 GPa, a new high-pressure phase is observed, which has been proposed to be bcc.[7] A high-pressure bcc structure has also been found in Sb at 28 GPa and in Bi at 7.7 GPa.[16] In contrast, the sh phase of Si and Ge transforms to the hcp structure.[17]

To date, despite these data, no full theoretical description of the phase stability in P under extreme high pressure has been reported. There are a few DFT calculations on the structural stability of P under pressure.[13, 14] Using the pseudopotential method, Chang and Cohen [13] reproduced the A17→A7→sc phase transitions, with the crystal energy of the A7 phase being shifted by 2.3 mRy, but failed to find any stable closed-packed P phase at high pressure. In contrast, Sasaki *et al.* [14] inferred a sc-bcc transition at a pressure of 135 GPa, rather far from the recent experimental observations.[7] This paper shows that ab-initio DFT calculations can successfully describe all the structural transitions in the phase diagram in P and, in particular, quantifies the sh-bcc transition, the highest-pressure structural transformation observed up to now for an elemental material.

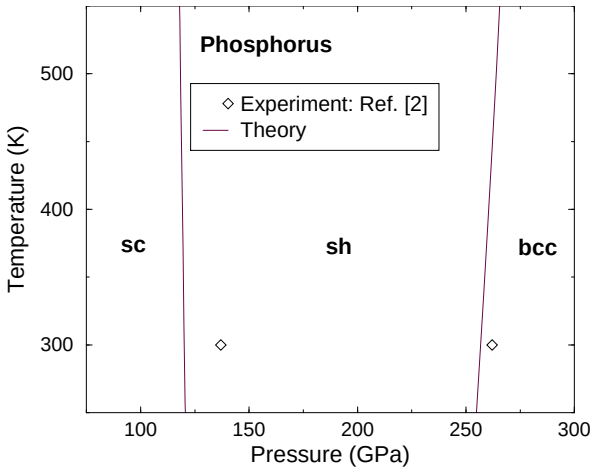

FIG. 1: Phase diagram of P at high pressures.

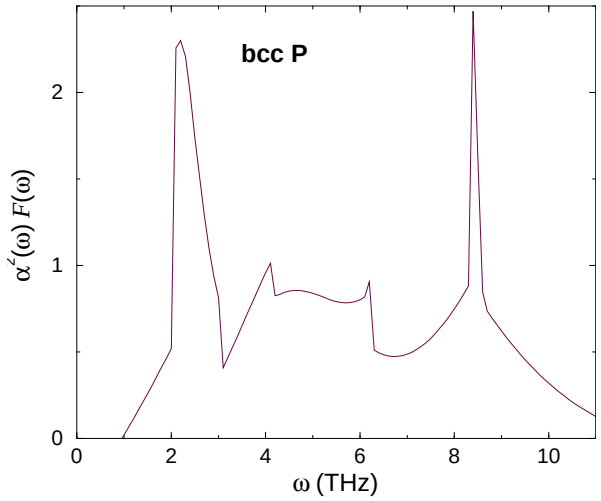

FIG. 2: The Eliashberg spectral function of bcc P.

The use of the Debye-Grüneisen theory within DFT calculations is the simplest way to investigate structural phase transitions at finite temperatures. The characteristic Debye temperature Θ_D, calculated in terms of the bulk modulus, can be used to constuct the free energy $F(T,V)$ as the function of Θ_D and V. The successful applicability of this model, in despite of its harmonic approximation for lattice vibrations, has been demonstrated [18] for some elemental materals under high pressure. To construct the phase diagram, the thermodynamical Gibbs potentials $G(P,T) = F(V,T) + PV$ are calculated and compared for various structures while the isothermal pressure dependence $P(V)$ is obtained by direct differentiation $P = -(\partial F/\partial V)_T$ for each structure. We use the full potential linearized augmented plane waves (WIEN) code [19], which is one of the most accurate DFT schemes. Exchange and correlation effects are treated using the generalized-gradient approximations [20] while *muffin-tin* radii of 1.7 a.u. are fixed for all structures. As Fig. 1 of the phase diagram of P shows, the calculations reproduce quantitatively well all available experimental data on the pressure induced structural transformations in P. In particular, at just above the critical pressure where the sh-bcc transition takes place, at 260 GPa the bcc phase is a real possibility and the bcc phase remains stable at still higher pressures. The free energy calculation of the bcc phase shows a minimum at 3.05 Å. We predict also that the sh-bcc transition has a positive dT/dP slope at room temperature.

Since the sc phase of P becomes superconducting (SC) below 10 K, one may expect similar electron-phonon interaction (EPI) strengths in P at higher pressures. Hence, a conventional s-wave pairing state may also arise in bcc P. We investigate this possibility by using a linear-response full-potential LMTO DFT method [21], which can describe the SC properties for sp materials with high accuracy [22] as well as those of d-metals under high pressure.[23] The calculated FP-LMTO electronic structure of bcc P is practically identical to that of the WIEN-code calculation. The phonon dispersions $\omega_m(\mathbf{q})$ and density of states $F(\omega)$ are obtained from this linear-response technique [21] and used to calculate the Eliashberg spectral function $\alpha^2(\omega)F(\omega)$ which defines the EPI strength $\lambda = \int_0^{\omega_{max}} \omega^{-1}\,\alpha^2(\omega)\,F(\omega)\,d\omega$. The function $\alpha^2(\omega)F(\omega)$, shown in Fig. 2, is dominated by the two optical peaks at 2.1 THz and 8.3 THz.

The SC transition temperature is calculated by means of the Allen-Dynes modified McMillan expression [26] $T_c = \frac{<\omega>}{1.2}\, exp\left[\frac{-1.04(1+\lambda)}{\lambda-\mu^*(1+0.62\lambda)}\right]$ using the calculated EPI strength and assuming a value of the Coulomb pseudopotential of μ^*=0.15 which was also used to calculate T_c for the sc phase of P. In bcc P we find T_c=19 K. Regarding the transport properties of bcc P in the normal state, the temperature dependence of the specific dc resistivity shows a crossover from power law to linear dependence at 50 K.

There is considerable current interest in technological spintronics applications, in which the spin of carriers is exploited to provide new functionality for microelectronic devices. Growth of P containing materials by thin film techniques, such as molecular beam epitaxy or pulsed laser deposition, has been developed to fabricate the class of wide gap phosphide ferromagnetic semiconductors.[10] Epitaxial thin film structures offer ideal opportunities to stabilize the bcc phase of P at ambient conditions using suitable growth templates such as the V(100), Fe(100) or Cr(100) substrates. Consequently, we now turn to study the electronic and magnetic properties of thin films of P (3-5 layers in thickness) embedded in ferromagnetic (FM) bcc-Fe. During the last decade considerable theoretical and experimental progress has been made towards the understanding of metallic magnetism in superlattices and multilayers. However, to date, no such investigations have been made for Fe/P.

The electronic structure of the $Fe_5/P_n/Fe_4$ (n=3,5) superlattices, with the lattice constant of bulk Fe, is cal-

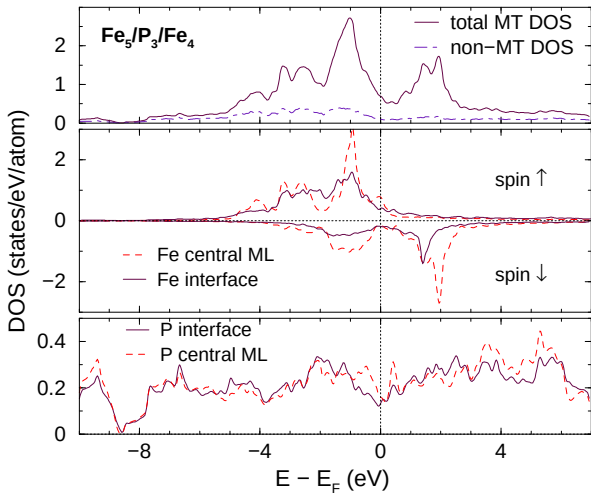

FIG. 3: Total and layer-resolved electronic DOS of the $Fe_5/P_3/Fe_4$ superlattices with the lattice constant of bulk Fe.

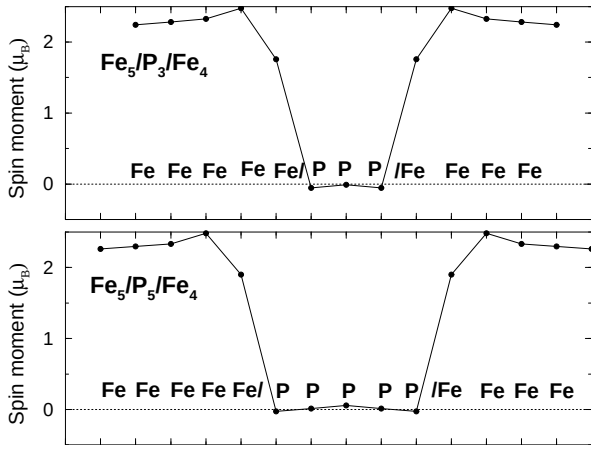

FIG. 4: Calculated layer-resolved spin moments of Fe and P in the $Fe_5/P_n/Fe_4$ (n=3,5) superlattices with the lattice constant of bulk Fe.

culated from the WIEN-code. Fig. 3 shows the total and layer-resolved electronic density of states (DOS) for $n = 3$. Evidently the DOS of phosphorus is fairly insensitive to monolayer (ML) position and p-d hybridization has broadened d-related peaks in the Fe interface DOS. Following on from this Fig. 4 shows the layer-resolved spin magnetic moments and the spin magnetic moment per atom on the Fe interface layer is about 20 % smaller than that of bulk bcc Fe whereas the second Fe layer from the ideally sharp Fe/P interface has an enhanced local spin moment compared to that of bulk Fe. The P atoms away from the interface have no induced magnetic moments. The spin magnetic moment on the P interface atoms are tiny and antiparallel to the Fe magnetization direction. Thus, the total magnetic moments of the Fe/P/Fe superlattices, which are almost independent of the thickness of P, are slightly reduced from those of a relevant pure Fe system due to the AF Fe-P interface coupling. Obviously, this effect would be important for superlattices with thin Fe slabs. We note that a similar but more pronounced AF coupling takes place at the Fe/V (001) interface.[24, 25]

The proximity effect in FM/SC heterostructures means that the Cooper pair amplitude in an exchange field does not decay exponentially to zero on the FM side but oscillates with decreasing amplitude as a function of the distance from the interface. These oscillations occurring in what is known as the Fulde-Ferrell-Larkin-Ovchinnikov state [28] may lead striking changes in the SC transition temperature (as observed in Fe/V and Fe/Nb heterostructures [27]) as a function of the FM slab thickness d_{Fe}. We suggest that Fe/P heterostructures may show similar effects.

Another interesting application of the SC state in the stabilized bcc phase of P might be available with V/Fe/P junctions, in which thin FM films are sandwiched between two superconductors with differing SC transition temperatures. Such systems support spontaneous currents parallel to the FM/SC interface while the spin polarization of these currents depends on band filling [29] and, hence, can be readily adjusted.

In *summary*, our study of P under high pressure based upon DFT and Debye model calculations produces a pressure-temperature phase diagram in good agreement with experiment. Pressure-induced metallization, attributed to the strong P-P interactions, is enhanced in the bcc phase which is stable for pressures in excess of 265 GPa. We have demonstrated that bcc-P might be a *s*-wave superconductor below 19 K owing primarily to strong EPI for the phonon bands along [110]. Finally, we predict that the SC properties of bcc-P can be realized in Fe/P heterostructures in which the bcc phase of P should be stable.

The authors acknowledge support from the EPSRC (U.K.). S.Y.S acknowledges the support from the grants NSF DMR 0238188 and NJSGC 02-42.

[1] K. Shimizu, T. Kimura, S. Furomoto, K. Takeda, K. Kontani, Y. Onuki, K. Amaya, Nature **412**, 316 (2000).
[2] K. Shimizu, H. Ishikawa, D. Takao, T. Yagi, K. Amaya, Nature **419**, 597 (2002).
[3] N.W. Ashcroft, Nature **419**, 569 (2002).
[4] I.I. Mazin, D.A. Papaconstantopoulos, and M.J. Mehl, Phys. Rev. B **65**, 100511, (2002).
[5] S.K. Bose, O.V. Dolgov, J. Kortus, O. Jepsen, and O.K. Andersen, cond-mat/0207318.
[6] T. Kikegawa and H. Iwasaki, Acta Crystallogr., Sect. B: Struct. Sci. **39**, 158 (1983).
[7] Y. Akahama, H. Kawamura, S. Carlson, T. Le Bihan,

D. Hausermann, Phys. Rev. B **61**, 3139 (2000).
[8] Y. Akahama, M. Kobayashi, and H. Kawamura, Phys. Rev. B **59**, 8520 (1999).
[9] H. Kawamura, I. Shirotani, K. Tachikawa, Solid State Commun. **49**, 879 (1984); **54**, 775 (1985).
[10] S.J. Pearton, C.R. Abernathy, M.E. Overberg, G.T. Thaler, D.P. Norton, N. Theodoropoulou, A.F. Hebard, Y.D. Park, F. Ren, J. Kim, and L.A. Boatner, J. Appl. Phys. **93**, 1 (2003).
[11] For a review, see, *e.g.*, *Theory of the Inhomogeneous Electron Gas*, edited by S. Lundqvist and S.H. March (Plenum, New York, 1983).
[12] For a review, see, e.g., S. Baroni, S. de Gironcoli, A. Dal Corso, Rev. Mod. Phys. **73**, 515-563 (2001).
[13] K.J. Chang and M.L. Cohen, Phys. Rev. B **33**, 6177 (1986).
[14] T. Sasaki, K. Shindo, K. Niizeki, A. Morita, J. Phys. Soc. Jpn. **57**, 978 (1988).
[15] M. Rajagopalan, M. Alouani, and N.E. Christensen, J. Low Temperature Physics **75**, 1 (1988).
[16] K.K. Aoki, S. Fujiwara, and M. Kusakabe, Solid State Commun. **45**, 161 (1983); J. Phys. Soc. Jpn. **51**, 3826 (1982).
[17] Y.K. Vohra, K.E. Brister, S. Desgreniers, A.L. Rooff, K.J. Chang, M.L. Cohen, Phys. Rev. Lett. **56**, 1944 (1986).
[18] S.A. Ostanin and V.Yu. Trubitsin, Phys. Rev. B **57**, 13485 (1998).
[19] P. Blaha, K. Schwarz, and J. Luitz, WIEN97 (Vienna University of Technology, 1997); P. Blaha, K. Schwarz, P. Sorantin, and S.B. Trickey, Comput. Phys. Commun. **59**, 399 (1990).
[20] J.P. Perdew, K. Burke, M. Ernzerhof, Phys. Rev. Lett. **77**, 3865 (1996).
[21] S.Y. Savrasov, Phys. Rev. B **54**, 16470 (1996).
[22] Y. Kong, O.V. Dolgov, O. Jepsen, and O.K. Andersen, Phys. Rev. B **64**, 020501 (2001).
[23] S. Ostanin, V. Trubitsin, S. Savrasov, M. Alouani, and H. Dreyssé, Comp. Mater. Sci. **17**, 202 (2000).
[24] B. Hjörvarsson, J.A. Dura, P. Isberg, T. Watanabe, T.J. Udovic, G. Andersson, and C.F. Majkrzak, Phys. Rev. Lett. **79**, 901 (1997).
[25] S. Ostanin, V.M. Uzdin, C. Demangeat, J.M. Wills, M. Alouani, and H. Dreyssé, Phys. Rev. B **61**, 4870 (2000).
[26] P.B. Allen and R.C. Dynes, Phys. Rev. B **12**, 905 (1975).
[27] H.K. Wong, B.Y. Jin, H.Q. Yang, J.B. Ketterson, J.E. Hillard, J. Low Temp. Phys. **63**, 307 (1986).
[28] P. Fulde and A. Ferrell, Phys. Rev. **135**, A550 (1964); A. Larkin and Y. Ovchinnikov, Sov. Phys. JETP **20**, 762 (1965).
[29] M. Krawiec, B.L. Gyorffy, and J.F. Annett, Phys. Rev. B **66**, 172505 (2002).